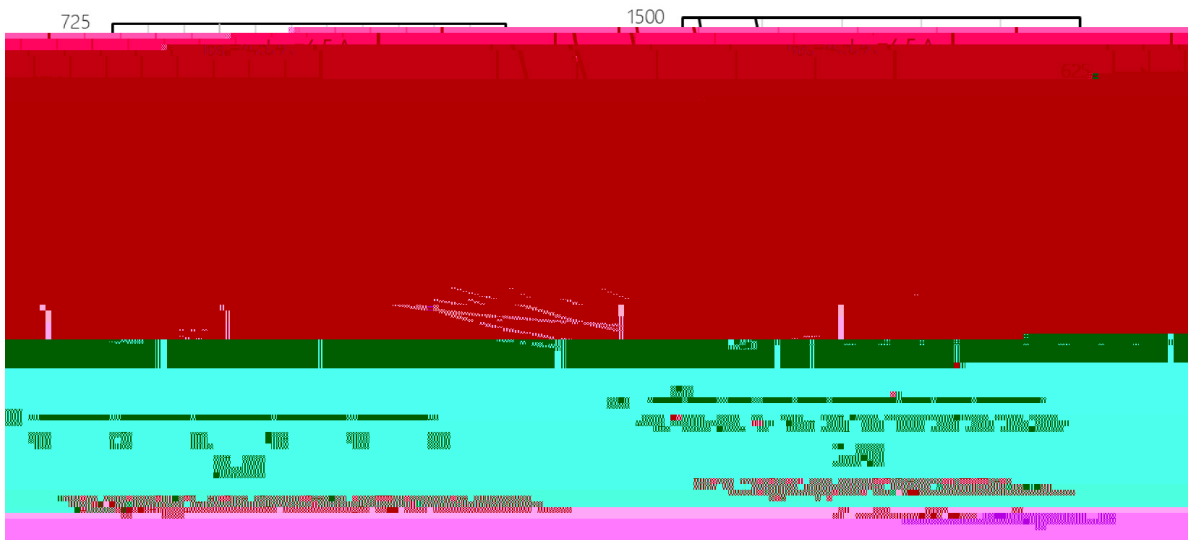
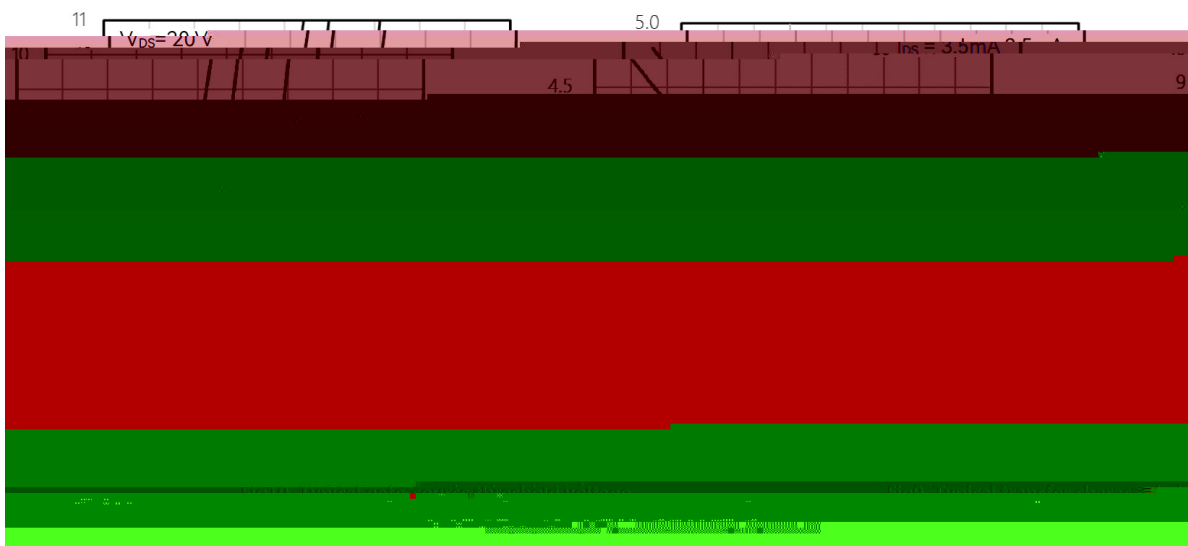
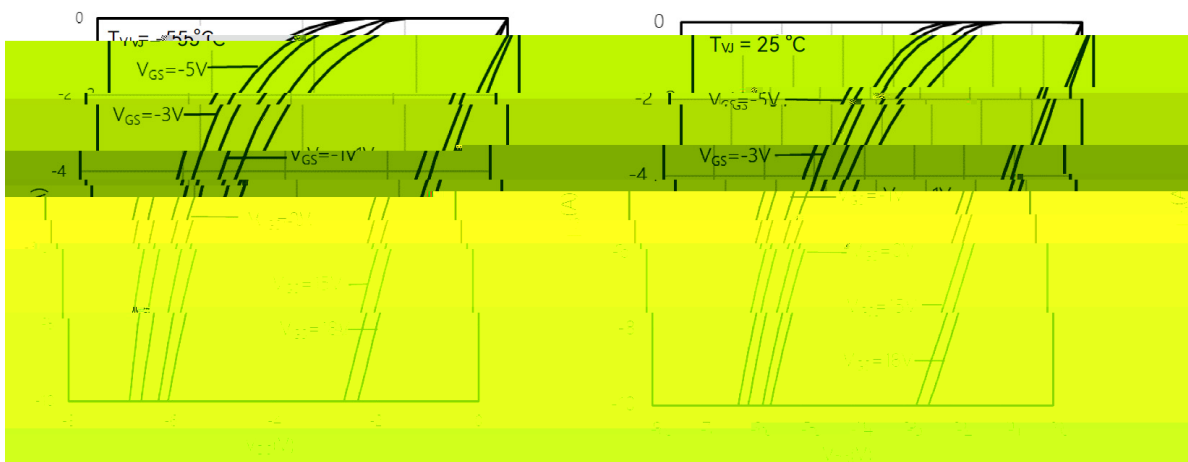


/ Electrical Characteristics(Tc=25)

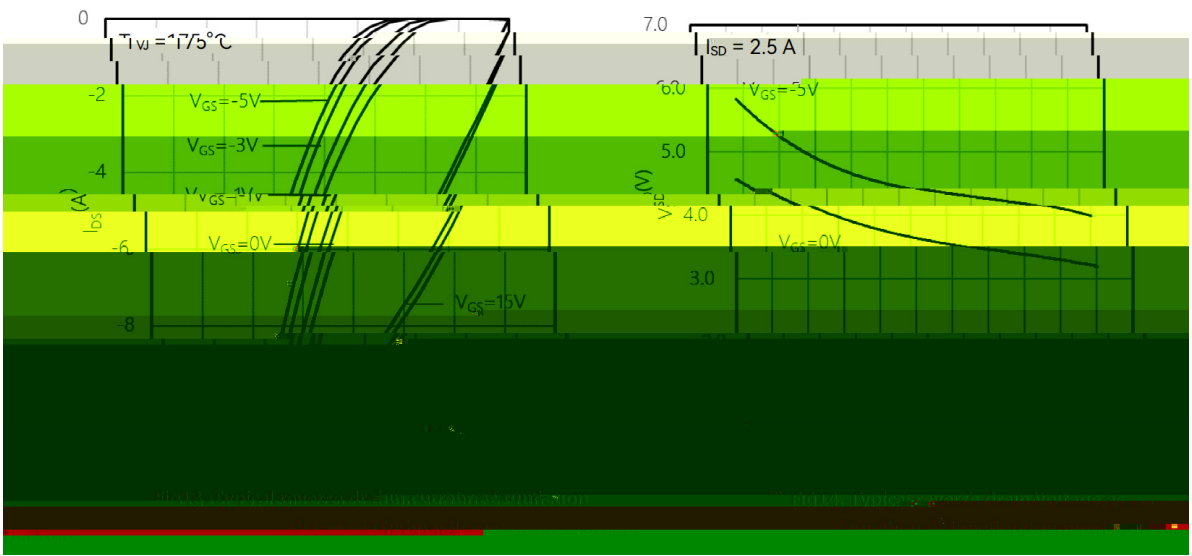
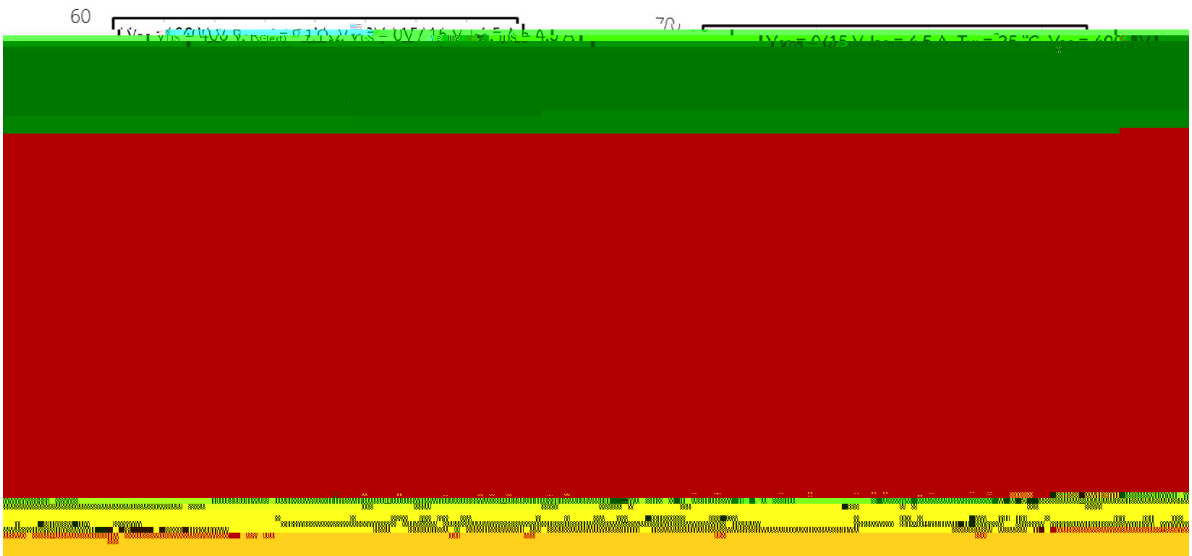
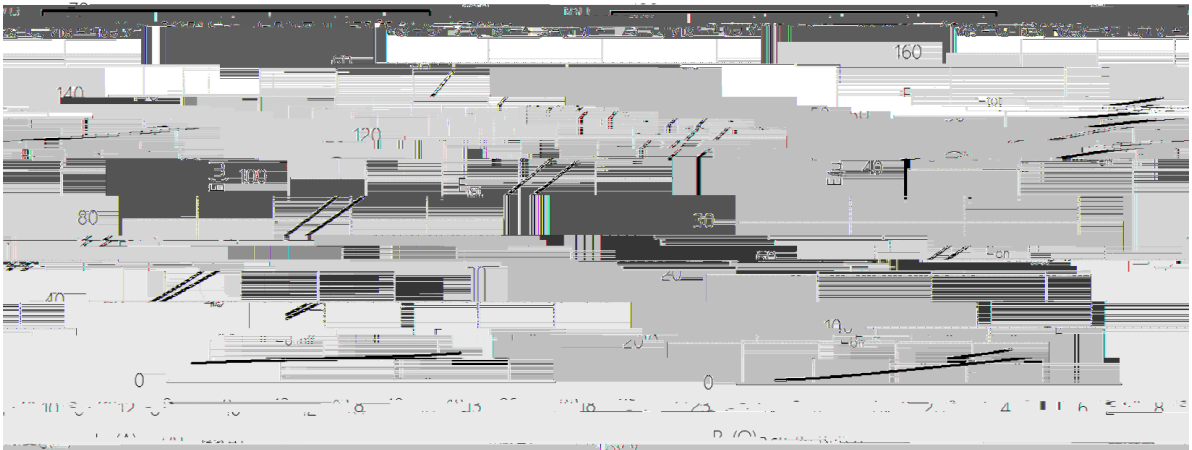
		μ				
-						μ
-						
						Ω

/ Electrical Characteristic Curve



11 Typical reverse drain current vs. drain-source voltage
 12 Typical gate charge vs. drain-source voltage
 13 Typical reverse drain current vs. drain-source voltage at different temperatures

/ ElectricalCharacteristicCurve



energy losses as a function of
vice own body diode: $V_{GS} = 0\text{V}$.

Fig18. Typical switching energy losses as a function
of I_{DS} . 2nd device own body diode: $V_{GS} = 0\text{V}$.

Fig17. Typical switching
gate resistance. 2nd device

/ Electrical Characteristic Curve

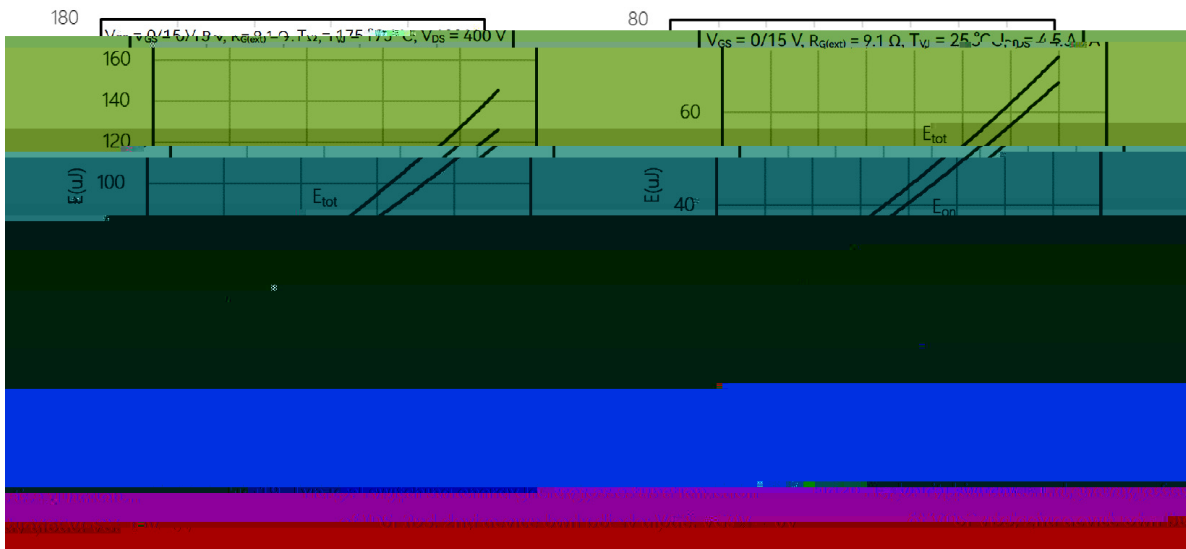
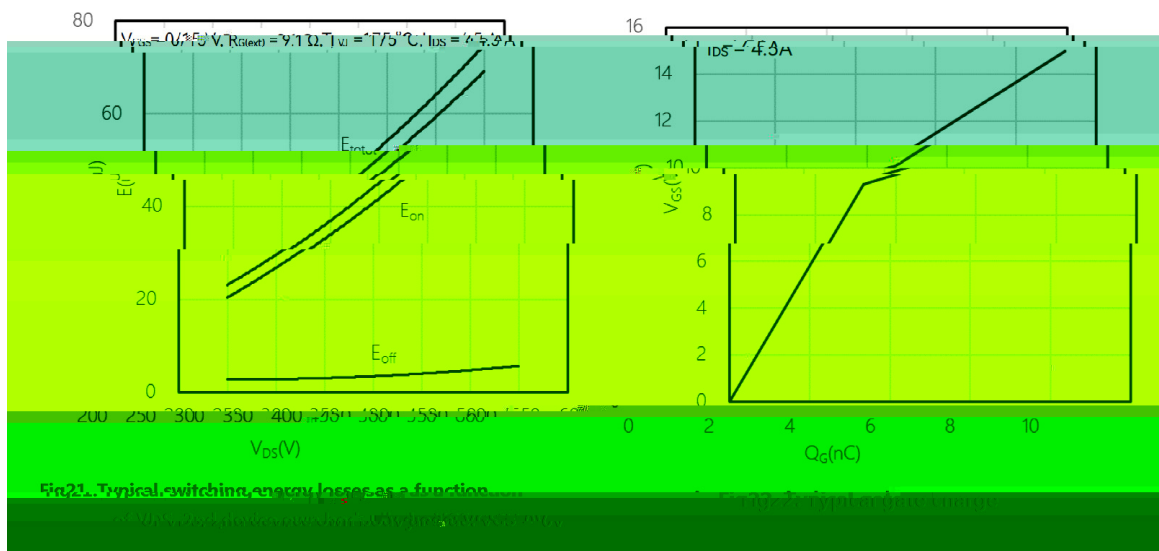
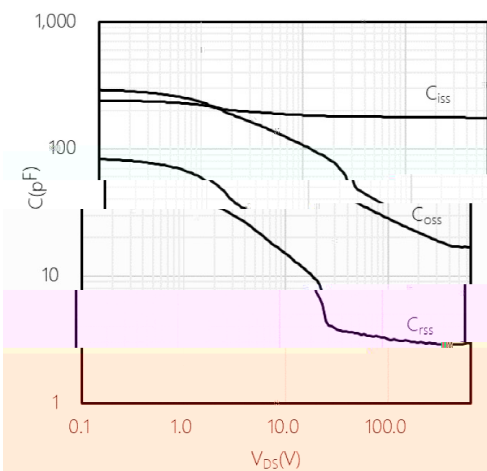
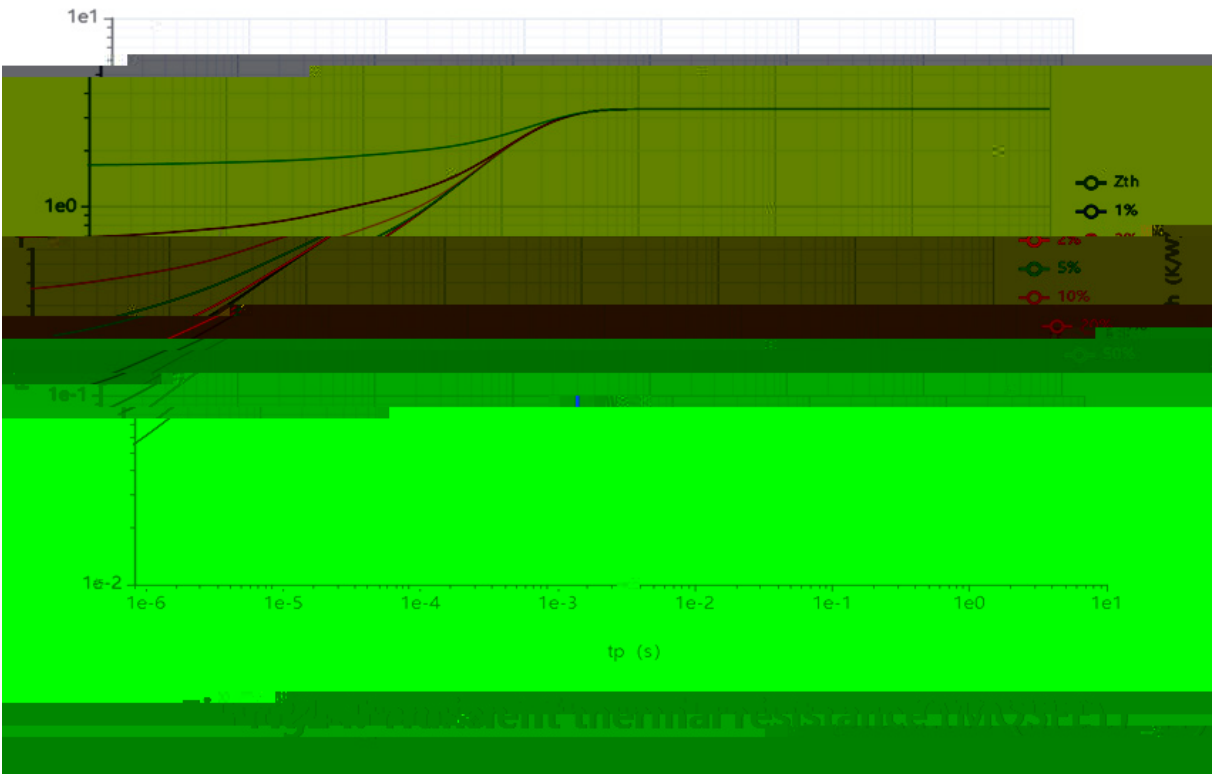


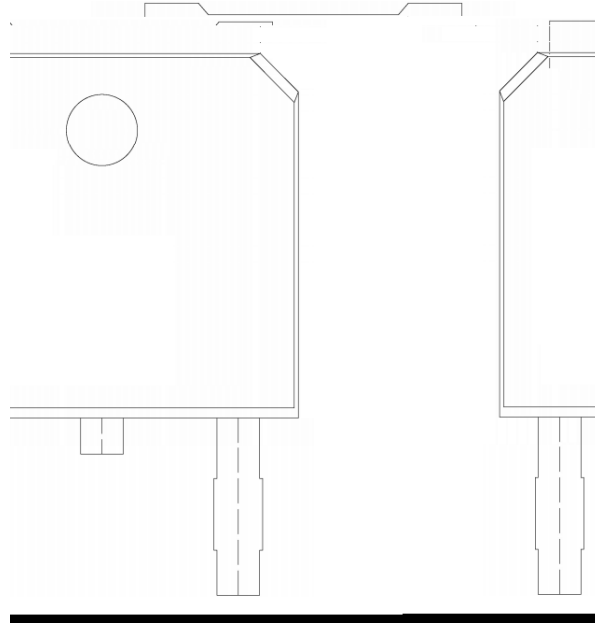
Fig23. Typical capacitance as a function of drain-source voltage

/ Electrical Characteristic Curve



BRSC65R480ZDP

/ Marking Instructions



65R480Z

SC

() / Temperature Profile for IR Reflow Soldering(Pb-Free)
